NSN 5962-01-483-1901

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Maximum Power Dissipation Rating:
500.0 milliwatts
Operating Tempurature Range:
-55.0/+125.0 degrees celsius
Storage Tempurature Range:
-65.0/+150.0 degrees celsius
Features Provided:
Monolithic and ultraviolet erasable
Inclosure Configuration:
Leaded chip carrier
Output Logic Form:
Complementary-metal oxide-semiconductor logic
Product Name:
Microcircuit, memory, digital, cmos, 262, 144-bit, uv erasable prom, monolithic silicon
Voltage Rating And Type Per Characteristic:
4.5 volts power source and 5.5 volts power source
Memory Device Type:
Eprom
Special Features:
This item is to be built from an altered item under smd 5962-8606302xa
Test Data Document:
96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.).
Terminal Type And Quantity:
32 j-hook
Shelf Life:
N/a
Unit Of Measure:
Demilitarization:
Yes - demil/mli
Fiig:
A458a0